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N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}$ (m Ω)(TYP.)	I _D (A) ^{a, e}	Q _g (TYP.)			
30	2.1at V _{GS} = 10 V	120	142 nC			
30	2.9at V _{GS} = 4.5 V	100	142110			

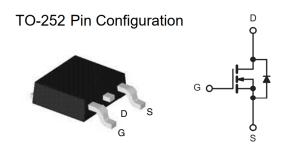
FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested
- · Compliant to RoHS Directive 2011/65/EU





- OR-ing
- Server
- DC/DC



Top View

N-Channel MOSFET

Parameter	Symbol	Limit	Unit		
Drain-Source Voltage	V _{DS}	30	V		
Gate-Source Voltage		V _{GS}	± 20		
	T _C = 25 °C		120 ^{a, e}		
Continuous Drain Current (T _J = 175 °C)	T _C = 70 °C	_	98 ^e	A	
Continuous Drain Current (1, = 175 C)	T _A = 25 °C	I _D	35.8 ^{b, c}		
	T _A = 70 °C		27 ^{b, c}		
Pulsed Drain Current	I _{DM}	360			
Avalanche Current Pulse	L = 0.1 mH	I _{AS}	39		
Single Pulse Avalanche Energy	L = 0.11IIII	E _{AS}	714	mJ	
Continuous Source-Drain Diode Current	T _C = 25 °C		120 ^{a, e}	Α	
Continuous Source-Drain Diode Current	T _A = 25 °C	I _S	3.13 ^{b, c}		
	T _C = 25 °C		250 ^a	w	
Mayirayaa Dayyaa Digainatiga	T _C = 70 °C	P _D	175		
Maximum Power Dissipation	T _A = 25 °C	I D	3.75 ^{b, c}		
	T _A = 70 °C		2.63 ^{b, c}		
Operating Junction and Storage Temperature Ra	T _J , T _{stg}	- 55 to 175	°C		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Тур.	Max.	Unit	
Maximum Junction-to-Ambient ^{b, d}	t ≤ 10 sec	R _{thJA}	32	40	°C/W	
Maximum Junction-to-Case	Steady State	R _{thJC}	0.5	0.6	- C/vv	

- a. Based on T_C = 25 °C.
 b. Surface mounted on 1" x 1" FR4 board.
 c. t = 10 sec.
 d. Maximum under steady state conditions is 90 °C/W.
- e. Calculated based on maximum junction temperature.





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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V, I}_{D} = 250 \mu\text{A}$	30			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = 250 μA		35		mV/°C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	ι _D – 230 μΑ		- 7.5			
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.5		2.5	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zara Cata Valtara Prain Current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current		$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$			10	10 µA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	120			Α	
		V _{GS} = 10 V, I _D = 30 A		2.1	2.5	mO	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 20 A		2.9	3.9		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 30 A		160		S	
Dynamic ^b	•						
Input Capacitance	C _{iss}			6910		pF	
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		746			
Reverse Transfer Capacitance	C _{rss}			906			
Total Gate Charge	Qg			142		nC	
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 30 \text{ A}$		12			
Gate-Drain Charge	Q _{gd}			95			
Gate Resistance	R_g	f = 1 MHz		2.8		Ω	
Turn-On Delay Time	t _{d(on)}			18			
Rise Time	t _r	$V_{DD} = 15 \text{ V}, R_{L} = 0.625 \Omega$		11		ns	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 30$ A, $V_{GEN} = 10$ V, $R_g = 1$ Ω		70			
Fall Time	t _f			10			
Turn-On Delay Time	t _{d(on)}			55			
Rise Time	t _r	V_{DD} = 15 V, R_{L} = 0.67 Ω		180			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 30 \text{ A}, \text{ V} \text{GEN} = 4.5 \text{ V}, \text{ R}_g = 1 \Omega$		55			
Fall Time	t _f			12		1	
Drain-Source Body Diode Characteristics	;						
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C			120	Α	
Pulse Diode Forward Current ^a	I _{SM}				360	^	
Body Diode Voltage	V _{SD}	I _S = 22 A		0.8	1.2	V	
Body Diode Reverse Recovery Time	t _{rr}			52		ns	
Body Diode Reverse Recovery Charge	Q _{rr}	I _F = 30 A, di/dt = 100 A/μs, T _J = 25 °C		70.2		nC	
Reverse Recovery Fall Time	t _a	1 _F = 30 Λ, αι/αι = 100 Λ/μs, 1 _J = 25 °C		27			
Reverse Recovery Rise Time	t _b			25		ns	

Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

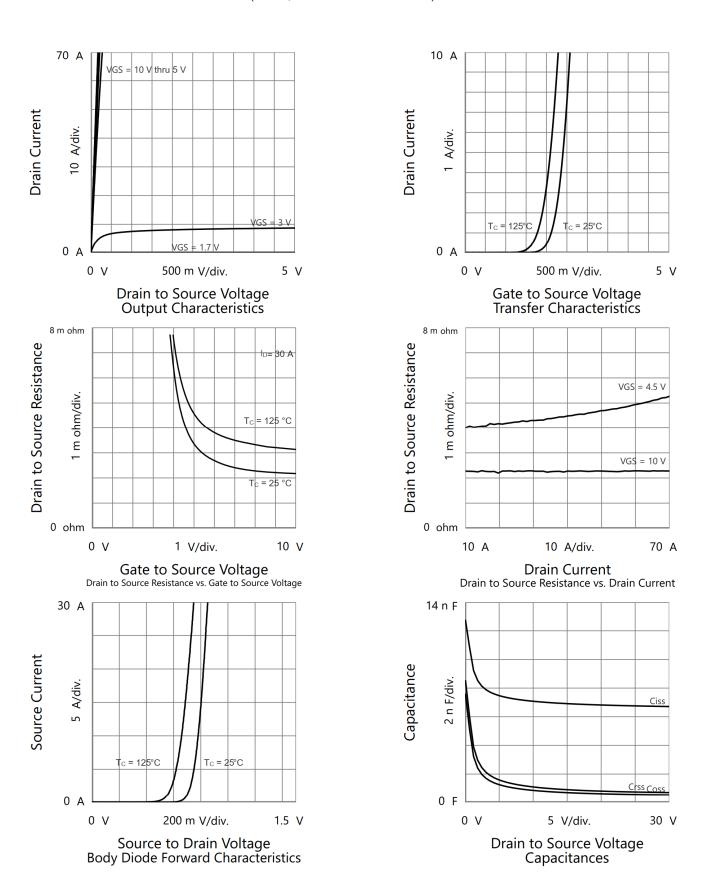
a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.





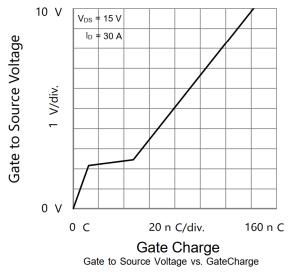
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

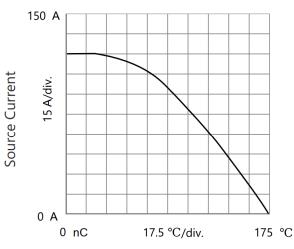






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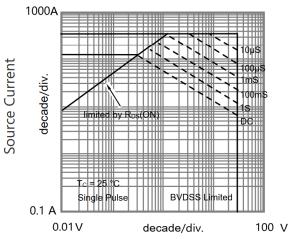




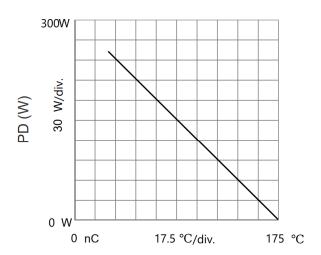
0 A
0 nC
17.5 °C/div.

T_C - Case Temperature

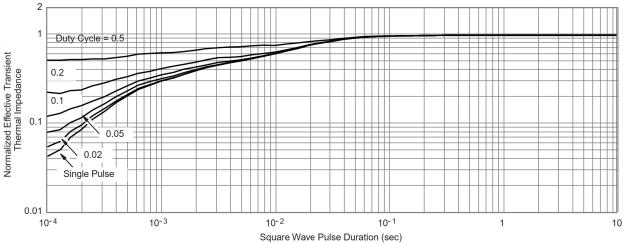
Current Derating



Source to Drain Voltage Safe Operating Area, Junction-to-Ambient



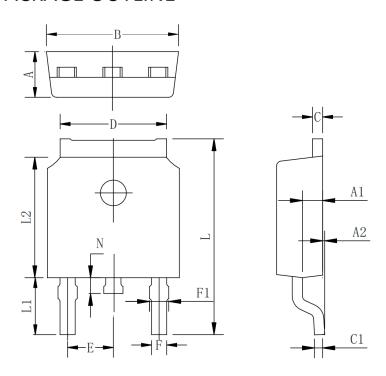
T_C - Case Temperature Power Derating



Normalized Thermal Transient Impedance, Junction-to-Case



TO-252-2L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

Symbol	Min	Тур	Max	
A	2.10	2.30	2.50	
A1	0.88	1.01	1.16	
A2	0.00	0.15	0.28	
В	6.40	6.60	6.80	
С	0.42	0.50	0.63	
C1	0.42	0.50	0.63	
D	5.08	5.32	5.65	
Е	2.286 TYP			
F	0.63	0.76	0.89	
F1	0.64	0.86	1.08	
L	9.30	9.90	10.80	
L1	2.4	2.8	3.6	
L2	5.90	6.10	6.55	
N	0.57	0.80	1.05	



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